TLP2409

1. Applications

- High-Speed Digital Interfacing for Instrumentation and Control Devices
- Industrial Inverters
- Switching Power Supplies

2. General

The Toshiba TLP2409 consists of a high output power infrared LED coupled with a high-speed photodiodetransistor chip. It is housed in the SO8 package. The TLP2409 features an operating temperature range of up to 125°C, making it ideal for applications like DC-DC converters and industrial equipment which require operations at high temperatures.

3. Features

- (1) Package: SO8
- (2) Propagation delay time: t_{pHL} = 0.8 $\mu s,\,t_{pLH}$ = 0.8 μs (max)@ R_L = 1.9 $k\Omega$
- (3) Operating temperature: -55 to 125 °C
- (4) Isolation voltage: 3750 Vrms (min)
- (5) TTL-compatible
- (6) Safety standards

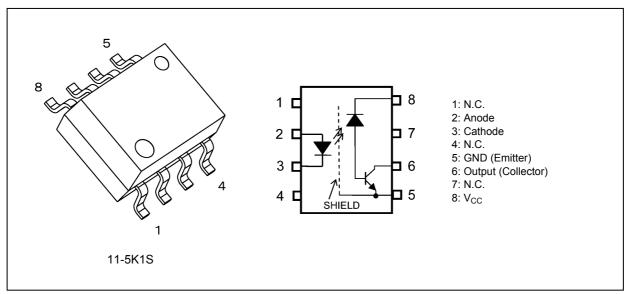
UL-recognized: UL 1577, File No.E67349

cUL-recognized: CSA Component Acceptance Service No.5A File No.E67349

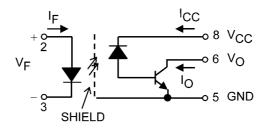
VDE-approved: EN 60747-5-5 (Note 1)

Note 1: When a VDE approved type is needed, please designate the **Option (V4)**.

4. Packaging and Pin Assignment



5. Internal Circuit (Note)



Note: A $0.1 \mu F$ bypass capacitor must be connected between pin 8 and pin 5.

6. Principle of Operation

6.1. Mechanical Parameters

Characteristics	Min	Unit
Creepage distances	4.0	mm
Clearance	4.0	
Internal isolation thickness		

7. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25$ °C)

	Characteristics		Symbol	Note	Rating	Unit
LED	Input forward current	(T _a ≤ 110 °C)	١ _F		25	mA
	Input forward current derating	(T _a ≥ 110 °C)	$\Delta I_F / \Delta T_a$		-0.67	mA/°C
	Input forward current (pulsed)	(T _a ≤ 110 °C)	I _{FP}	(Note 1)	50	mA
	Input forward current derating (pulsed)	$(T_a \ge 110 \ ^\circ C)$	$\Delta I_{FP} / \Delta T_a$		-1.34	mA/°C
	Input reverse voltage		V _R		5	V
	Input power dissipation	(T _a ≤ 110 °C)	PD		40	mW
	Input power dissipation derating	(T _a ≥ 110 °C)	$\Delta P_D / \Delta T_a$		-1.0	mW/°C
Detector	Output current	(T _a ≤ 95 °C)	Ι _Ο		16	mA
	Output current derating	(T _a ≥ 95 °C)	$\Delta I_0 / \Delta T_a$		-0.3	mA/°C
	Output voltage		Vo		-0.5 to 20	V
	Supply voltage		V _{CC}		-0.5 to 30	
	Output power dissipation	$(T_a \le 95 \ ^\circ C)$	Po		100	mW
	Output power dissipation derating	$(T_a \ge 95 \ ^\circ C)$	$\Delta P_0 / \Delta T_a$		-1.8	mW/°C
Common	Operating temperature		T _{opr}		-55 to 125	°C
	Storage temperature		T _{stg}		-55 to 150	
	Lead soldering temperature	(10 s)	T _{sol}		260	
	Isolation voltage	AC, 60 s, R.H. \leq 60 %	BVS	(Note 2)	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width (PW) \leq 1 ms, duty = 50 %

Note 2: This device is considered as a two-terminal device: Pins 1, 2, 3 and 4 are shorted together, and pins 5, 6, 7 and 8 are shorted together.

8. Recommended Operating Conditions (Note)

Characteristics	Symbol	Note	Min	Тур.	Max	Unit
Input forward current	I _F		—	—	15	mA
Output current	Ι _Ο		_	_	7	
Operating temperature	T _{opr}		-55	_	125	٦°

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this datasheet should also be considered.

9. Electrical Characteristics (Note) (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Input forward voltage	V _F		—	I _F = 16 mA	1.40	1.57	1.80	V
Input forward voltage temperature coefficient	$\Delta V_F / \Delta T_a$		—	I _F = 16 mA		-2	_	mV/°C
Input reverse current	I _R		_	V _R = 3 V	_	_	10	μA
Input capacitance	Ct		—	V _F = 0 V, f = 1 MHz		60	_	pF
High-level output current	I _{OH}		—	$I_{\rm F}$ = 0 mA, $V_{\rm CC}$ = $V_{\rm O}$ = 5.5 V		3	500	nA
				$I_F = 0 \text{ mA}, V_{CC} = 30 \text{ V}, V_O = 20 \text{ V}$			5	μΑ
				I _F = 0 mA, V _{CC} = 30 V, V _O = 20 V, T _a = 100 °C	_	_	50	
Low-level output voltage	V _{OL}		—	I _F = 16 mA, V _{CC} = 4.5 V, I _O = 2.4 mA	_	_	0.4	V
Current transfer ratio	I _O /I _F		—	I_F = 16 mA, V_{CC} = 4.5 V, V_O = 0.4 V	20	_	—	%
High-level supply current	I _{CCH}		_	I _F = 0 mA, V _{CC} = 30 V	_	0.01	1	μA

Note: All typical values are at $T_a = 25$ °C.

10. Isolation Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Note	Test Conditions	Min	Тур.	Max	Unit
Total capacitance (input to output)	Cs	(Note 1)	V _S = 0 V, f = 1 MHz		1.0	—	pF
Isolation resistance	R _S	(Note 1)	V_S = 500 V, R.H. ≤ 60 %	10 ¹²	1014	_	Ω
Isolation voltage	BVS		AC, 60 s	3750	_	_	Vrms

Note 1: This device is considered as a two-terminal device: Pins 1, 2, 3 and 4 are shorted together, and pins 5, 6, 7 and 8 are shorted together.

11. Switching Characteristics (Unless otherwise specified, $T_a = 25$ °C, $V_{CC} = 5$ V)

Characteristics	Symbol	Note	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Propagation delay time (H/L)	t _{pHL}		Fig 12.1.1	$I_F = 0 \rightarrow 16 \text{ mA}, R_L = 1.9 \text{ k}\Omega$	—	_	0.8	μS
Propagation delay time (L/H)	t _{pLH}			I_F = 16 \rightarrow 0 mA, R _L = 1.9 k Ω	—	—	0.8	
High-level common-mode transient immunity	CM _H	(Note 1)	Fig 12.1.2	$I_F = 0 \text{ mA}, \text{ R}_L = 4.1 \text{ k}\Omega,$ $V_{CM} = 400 \text{ V}_{p-p}$	5000	10000		V/μs
Low-level common-mode transient immunity	CML	(Note 2)		I_F = 16 mA, R _L = 4.1 kΩ, V _{CM} = 400 V _{p-p}	-5000	-10000	_	

Note 1: CM_H is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic high state ($V_O > 2.0 V$).

Note 2: CM_L is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic low state (V_O < 0.8 V).

12. Test Circuits and Characteristics Curves

12.1. Test Circuits

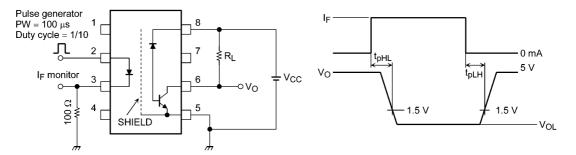


Fig. 12.1.1 Switching Time Test Circuit and Waveform

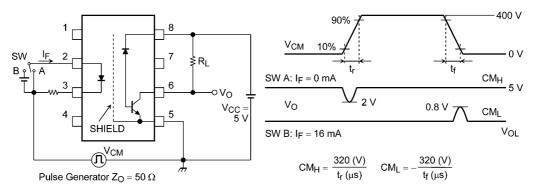


Fig. 12.1.2 Common-Mode Transient Immunity Test Circuit and Waveform

13. Soldering and Storage

13.1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

• When using soldering reflow.

The soldering temperature profile is based on the package surface temperature.

(See the figure shown below, which is based on the package surface temperature.)

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.

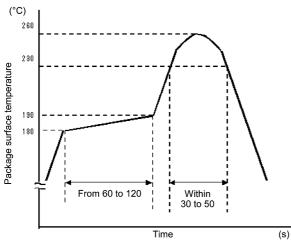


Fig. 13.1.1 An example of a temperature profile when lead(Pb)-free solder is used

• When using soldering flow

Preheat the device at a temperature of 150 °C (package surface temperature) for 60 to 120 seconds. Mounting condition of 260 °C within 10 seconds is recommended.

Flow soldering must be performed once.

When using soldering Iron

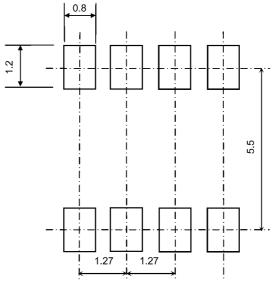
Complete soldering within 10 seconds for lead temperature not exceeding 260 $^\circ\!\mathrm{C}$ or within 3 seconds not exceeding 350 $^\circ\!\mathrm{C}$

Heating by soldering iron must be done only once per lead.

13.2. Precautions for General Storage

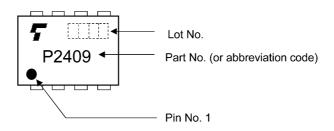
- Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- Follow the precautions printed on the packing label of the device for transportation and storage.
- Keep the storage location temperature and humidity within a range of 5°C to 35°C and 45% to 75%, respectively.
- Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- \cdot $\,$ When restoring devices after removal from their packing, use anti-static containers.
- Do not allow loads to be applied directly to devices while they are in storage.
- If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

14. Land Pattern Dimensions for Reference Only



Unit: mm

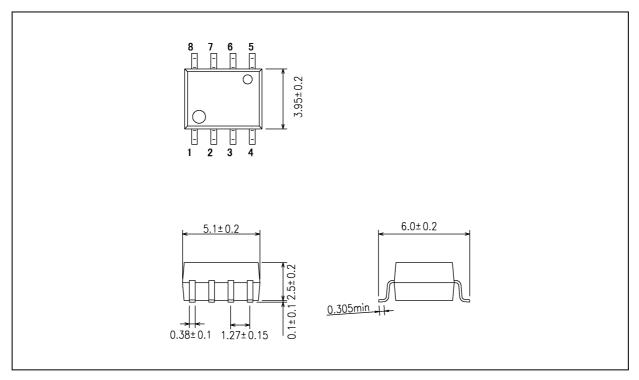
15. Marking



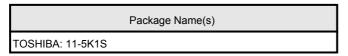
TLP2409

Package Dimensions

Unit: mm



Weight: 0.11 g (typ.)



RESTRICTIONS ON PRODUCT USE

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE").

Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant.

IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your TOSHIBA sales representative or contact us via our website.

- · Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
 applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- GaAs (Gallium Arsenide) is used in Product. GaAs is harmful to humans if consumed or absorbed, whether in the form of dust or vapor. Handle with care and do not break, cut, crush, grind, dissolve chemically or otherwise expose GaAs in Product.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

TOSHIBA ELECTRONIC DEVICES & STORAGE CORPORATION https://toshiba.semicon-storage.com/

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for High Speed Optocouplers category:

Click to view products by Toshiba manufacturer:

Other Similar products are found below :

HCPL-2201-300 TLP558(F) JAN4N24 610737H HCPL2630M HCPL2731SM HCPL2630SM PS9817A-1-F3-AX TLP2766A(E EL816S2(C)(TU)-F TLP281-4 PS9121-F3-AX PS9123-F3-AX HCPL2531S HCPL2631SD HCPL-4661-500E TLP118(TPL,E) TLP521-2XGB TLP621-2XGB 4N46-300E JANTXV4N24U SFH6318T 6N135-300E TIL198 TLP2309(TPL,E) TLP2355(TPL,E TLP521-4GR TLP521-4XGB TLP621-4X TLP621XSM IS281-4GB IS181GR ICPL2631 ICPL2630 ICPL2601 TLP714(F) TLP754(F) FOD260LSDV ACPL-M21L-500E ACPL-064L-500E PS2501-1XSM PS2505-1 PS2561L2-1-F3-A PS2913-1-F3-AX PS9821-2-F3-AX FOD0721R2 FODM8061R2V 6N135SDM 6N137SDM 6N138-000E